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The objective of this short term program was to initiate synthesis of a new class of light element materials with novel compositions that are isoelectronic to carbon (i.e. the number of valence electrons per atom is four) or related to Si ₃ N ₄ . The ultimate goal is to investigate their use in high pressure or laser ablation synthesis of extremely dense, superhard materials of the same composition that have structures and properties related to those of diamond. Examples of such systems include nitrogen rich compounds with stoichiometric compositions BeCN ₂ , LiBC ₂ N ₄ , LiAlC ₂ N ₄ , and C ₃ N ₄ . Progress on synthesis of the novel the phases BeCN ₂ , and LiAlC ₂ N ₄ , as well as initial high pressure studies of graphitic C ₃ N ₄ - LiBC ₄ N ₄ are described in this report. This work is continuing with full funding form ARO under grant DAA19-00-1-0471.				
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Sincerely,

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J Kwetaki)

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The use of novel precursor chemistry for synthesis of superhard materials,

Author

J. Kouvetakis

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1. Statement of the Problem

The objective of this short term program was to initiate synthesis of a new class of light element materials with novel compositions that are isoelectronic to carbon (i.e. the number of valence electrons per atom is four) or related to Si_3N_4 . The ultimate goal is to investigate their use in high pressure or laser ablation synthesis of extremely dense, superhard materials of the same composition that have structures and properties related to those of diamond. Examples of such systems include nitrogen rich compounds with stoichiometric compositions $BeCN_2$, $LiBC_2N_4$, $LiAlC_2N_4$, and C_3N_4 . Progress on synthesis of the novel the phases $BeCN_2$, and $LiAlC_2N_4$, as well as initial high pressure studies of graphitic $C_3N_4 - LiBC_4N_4$ are described below.

2. Summary of the Most Important Results

BeCN₂

The unknown BeCN₂ phase is of particular interest because it has been predicted to have optical and mechanical properties that are superior to those of c-BN: i.e. it is a direct-bandgap semiconductor with a bulk modulus of 333 GPa. Three-dimensional BeCN₂ is structurally analogous to wurtzitic BeSiN₂ (a structure very similar to the chalcopyrite structure) and has a lattice constant nearly identical to that of cubic BN. We have adopted two strategies for preparation of BeCN₂ thin films and bulk materials: (a) synthesis, and decomposition of molecular Be(NCN-SiMe₃)₂ and (b) direct synthesis of bulk BeCN₂ by soft-chemistry methods.

The first method is intended to synthesize thin films of BCN 2 via decomposition of the volatile molecular source Be(NCN-SiMe₃)₂ by elimination of one equivalent of Me₃Si-N=C=N-SiMe₃ as illustrated by Eq 1 below.

$$Be[NCN-SiMe_3]_2 \rightarrow BeCN_2 + Me_3Si-N=C=N-SiMe_3$$
 (1)

We have recently succeeded in synthesis and identification of small quantities of Me₃Si-N=C=N-SiMe₃, however, larger yields of the molecule are necessary to pursue a systematic study of CVD growth of films and coatings. Development of an improved synthesis is currently underway. The second method utilized low temperature reactions

of cyanamide (H₂CN₂) with Be[N(SiMe₃)₂]₂ to produce an intermediate solid precursor with composition Be(NCNH)₂•H₂CN₂ (see Eq. 2) which was characterized by spectroscopic methods (IR, mass spectrometry) and elemental analysis. Annealing of this solid, at 750°C in vacuum produced a colorless pollycrystalline material and memamine (see Eq. 3). Vibrational and combustion analysis data are consistent with "BeCN₂" although its structure still remains unsolved. The X-Ray powder pattern was virtually identical to earlier X-ray patterns of samples obtained from the reaction of equimolar amounts of BeCl₂ and TMS₂CN₂ (see Eq. 4).

$$Be[N(TMS)_{2}]_{2} + 3H_{2}CN_{2} \rightarrow "Be(NCNH)_{2} + 2HN(TMS)_{2}$$
(2)

$$"Be(NCNH)_{2} + H_{2}CN_{2}" \rightarrow "BeCN_{2}" + \frac{2}{3}Melamine$$
(3)

$$BeCl_{2} + TMS_{2}CN_{2} \rightarrow "BeCN_{2}" + 4TMS-Cl$$
(4)

The two different synthetic routes described by Equations 3 and 4 appear to yield the same product and our preliminary characterizations as well as the reaction intermediates clearly point to the desired BeCN₂ compound. A sturctural determination is, however, necessary to unambiguously identify this intriguing material. A possible polymeric structure of BeCN₂ is illustrated in Fig 1. The structure of BeSiN₂ analogous to dense BeCN₂ is also shown in Fig. 1.

Figure 1: Possible polymeric structure of Be(N=C=N). The structure of BeSiN₂ depicted as tetrahedra filled with Be (light) and Si (dark). Tetrahedra filled with the same atomsform zig-zag chains. The BeCN₂ compound is expected to have a similar dense structure.

LiAIC₂N₄

Initial attempts to prepare LiAlC₂N₄ involved reactions of LiAlH₄ as the Al and Li source, with (SiMe₃)₂CN₂ as the N-C-N source. As illustrated in the synthesis depicted by equation 5, complete elimination of gaseous SiMe₃H affords the ternary compound LiAlN₂CN₂. However, it was discovered that the crystalline solid Al(TMS-NCHN-TMS)₃ is the main product derived from this method instead (see Eqs 6 and 7 below).

$$LiAlH_4 + 2(SiMe_3)_2CN_2 \rightarrow LiAl(CN_2)_2 + 4SiMe_3H$$

$$LiAlH_4 + TMS_2CN_2 \rightarrow LiNCN-TMS + "AlH_3" + Me_3SiH$$

$$"AlH_4" + 3TMS_2CN_2 \rightarrow Al(TMS-NCHN-TMS)_3$$

$$(7)$$

Single-crystal X-ray diffraction revealed a novel structure for $(AlC_{21}H_{57}N_6Si_6)$ in which one aluminum atom is coordinated by six nitrogen atoms as shown in Fig. 2. Although $(AlC_{21}H_{57}N_6Si_6)$ was not the targeted product, its synthesis led to a new class of compounds incorporating the sterically crowded $(TMS-NCHN-TMS)^{-1}$ bidentate ligand. The analogous Ga compound $Ga(TMS-NCHN-TMS)_3$ as well as the related hydrides

HGa(TMS-NCHN-TMS)₂ and H₂Ga(TMS-NCHN-TMS) were also synthesized as volatile molecular species. Preliminary experiments suggest that the corresponding Al hydrides are also possible. These results indicate that the most important application of this new reaction method is the preparation of stable and volatile Al and Ga hydrides of the general formula RGaH₂ and R₂GaH [where R= (TMS-NCHN-TMS)]. These may be potentially useful as CVD precursors for growth of group III nitrides and related optoelectronic III-V materials. We are currently attempting to utilize this method to prepare the indium analogs RInH₂ and R₂InH as well as related unimolecular InN sources such as RInHN₃. The large chelating group R is the key to stabilizing such compounds which are typically considered to be unstable.

Figure 2: Molecular structure of Al(Me₃Si-N-C-N-SiMe₃)₃

Further attempts to synthesize the desired LiAl(NCN)₂ and possibly LiGa(NCN)₂involve reactions of alternative lithium, Al and Ga sources such as LiAlCl₄ and LiGaCl₄. We found that the reaction of LiAlCl₄ with Me₃Si-N=C=N-SiMe₃ at 650 °C results in a pollycrystalline colorless material which displays lattice modes consistent with a three dimensional inorganic solid. The IR spectrum is very simple and shows a sharp peak at 2190 cm⁻¹ corresponding to v_{as} for the linear N=C=N⁻² moiety, and additional peaks at 536 cm⁻¹ and 470 cm⁻¹ which can be assigned to metal-carbon and metal-nitrogen lattice modes. Because the anion [Al(NCN)₂] is isoelectronic with Si(NCN)₂, we postulate that Li[Al(NCN)₂] may have a framework structure similar to that of Si(NCN)₂. This is essentially that of crystobalite SiO₂ in which the –O⁻² anion is replaced by the linear anion (–N=C=N-)⁻². The lithium counterions will probably occupy the interstitial tetrahedral sites thus formic the classic filled crystoballite structure. An excellent example of a filled crystoballite is LiPN₂ which is shown in Fig 3. Structure elucidation of Li[Al(NCN)₂] is currently in progress.

Figure 3: Structure of LiPN₂. The PN₂ array mimics that of isoelectronic SiO2 and the Li ions are sitting in interstitial tetrahedral sites.

C₃N₄ and LiBC₄N₄ under high pressure.

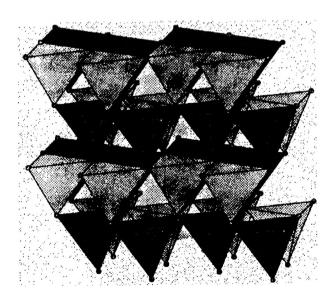
High pressure studies of C₃N₄ and diamond like LiBC₄N₄ were initiated with this project. Preliminary results results show that of the latter can be used to form pure and crystalline B-C-N with graphite like structure at 100 Kbar and 900°C (see D. Williams et al. J Am. Chem. Soc. 2000, 122, 7735) Experiments aimed to convert this compound into diamond-like dense structures are continuing in collaboration with Prof. Badding at Penn State University.

3. Personnel Supported

Cole Ritter
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Possible polymeric structure of Be(N=C=N).

Figure 1. (top) Possible polymeric structure of Be(N=C=N). The structure of BeSiN₂ depicted as tetrahedra filled with Be (light) and Si (dark). (bottom) Tetrahedra filled with the same atoms form zig-zag chains. The three dimensional BeCN₂ compound is expected to have a similar dense structure.



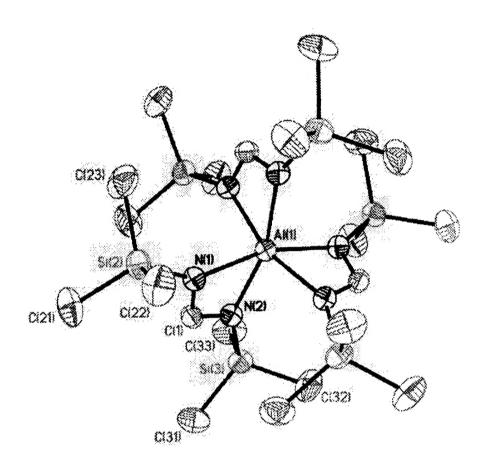


Figure 2. Molecular structure of Al(Me₃Si-N-C-N-SiMe₃)₃

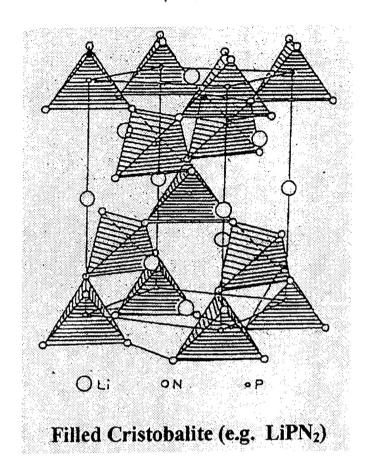


Figure 3. Structure of LiPN₂. The PN₂ array mimics that of isoelectronic SiO₂ and the Li ions are sitting in interstitial tetrahedral sites.